

# UTC UNISONIC TECHNOLOGIES CO., LTD

**Preliminary JFET** 

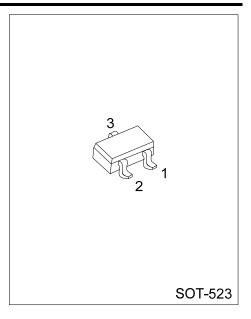
# **N-CHANNEL JUNCTION FIELD EFFECT TRANSISTOR**

#### DESCRIPTION

The UTC TF215 is an N-channel junction field effect transistor, and it can be specially used in electronic condenser microphone.

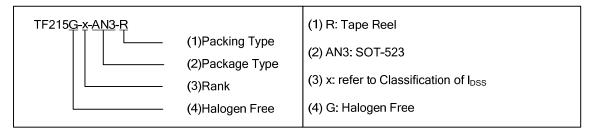
#### **FEATURES**

- \* Good voltage characteristics and transient characteristics.
- \* Halogen Free



#### **ORDERING INFORMATION**

Ordering Number	Dookogo	Pin Assignment			Dooking	
Ordering Number	Package	1	2	3	Packing	
TF215G-x-AN3-R	SOT-523	S	D	G	Tape Reel	



#### **MARKING**

TF215-D4	TF215-D5			
<u>—————————————————————————————————————</u>	<u> </u>			
D4	D5			

### ■ ABSOLUTE MAXIMUM RATING (Ta=25°C, unless otherwise specified)

PARAMETER	SYMBOL	RATINGS	UNIT
Gate to Drain Voltage	$V_{GDO}$	-20	V
Gate Current	l <sub>G</sub>	10	mA
Drain Current	I <sub>D</sub>	1	mA
Power Dissipation	P <sub>D</sub>	100	mW
Junction Temperature	TJ	150	°C
Storage Temperature	T <sub>STG</sub>	-55~+150	°C

Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

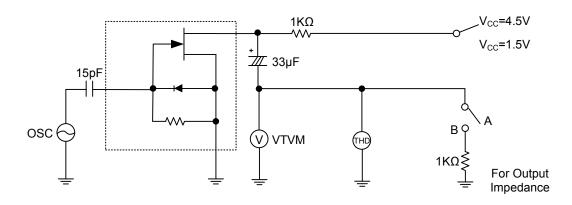
# ■ **ELECTRICAL CHARACTERISTICS** (T<sub>a</sub>=25°C, unless otherwise specified)

					1	
PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
G-D Breakdown Voltage	$BV_GDO$	I <sub>G</sub> =-100μA	-20			V
Gate Off Voltage	$V_{GS(OFF)}$	$V_{DS}$ =5.0V, $I_{D}$ =1 $\mu$ A	-0.2	-0.6	-1.0	V
Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =5.0V, V <sub>GS</sub> =0	140		350	μΑ
Forward Transfer Admittance	YFS	V <sub>DS</sub> =2.0V, V <sub>GS</sub> =0, f=1KHz	8.0	1.2		mS
Input Capacitance	CISS	V <sub>DS</sub> =5.0V, V <sub>GS</sub> =0, f=1MHz		3.5		pF
Reverse Transfer Capacitance	CRSS	V <sub>DS</sub> =5.0V, V <sub>GS</sub> =0, f=1MHz		0.65		pF
Voltage Gain	$G_V$	V <sub>IN</sub> =10mV, f=1KHz		-3.0		dB
Reduced Voltage Characteristic	$\triangle G_VV$	V <sub>IN</sub> =10mV, f=1KHz V <sub>CC</sub> =4.5→1.5V		-1.2	-3.5	dB
Frequency Characteristic	$ riangle G_{Vf}$	f=1KHz~110Hz			-1.0	dB
Input Resistance	$Z_{IN}$	f=1KHz	25			ΜΩ
Output Resistance	Zo	f=1KHz		1000		Ω
Total Harmonic Distortion	THD	V <sub>IN</sub> =30mV, f=1KHz		1.2		%
Output Noise Voltage	$V_{NO}$	V <sub>IN</sub> =0, A Curve			-110	dB

# ■ CLASSIFICATION OF I<sub>DSS</sub>

RANK	D4	D5
RANGE	140-240	210-350

## ■ TEST CIRCUIT (Ta=25°C)



UTC assumes no responsibility for equipment failures that result from using products at values that exceed, even momentarily, rated values (such as maximum ratings, operating condition ranges, or other parameters) listed in products specifications of any and all UTC products described or contained herein. UTC products are not designed for use in life support appliances, devices or systems where malfunction of these products can be reasonably expected to result in personal injury. Reproduction in whole or in part is prohibited without the prior written consent of the copyright owner. The information presented in this document does not form part of any quotation or contract, is believed to be accurate and reliable and may be changed without notice.